



DMTH6006SPS

Product Summary

BV _{DSS}	R _{DS(ON)} MAX	I _{D MAX} T _C = +25°С
60V	$6.2m\Omega @ V_{GS} = 10V$	100A

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Synchronus Rectifier
- DC-DC Converters
- Power Management

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

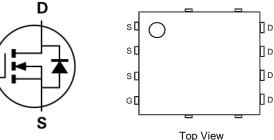
Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (93)
- Weight: 0.097 grams (Approximate)





Internal Schematic

Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH6006SPS-13	PowerDI5060-8	2,500 / Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

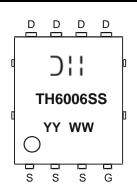
Lead-tree. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

G

<1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



) | | = Manufacturer's Marking
TH6006SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 19 = 2019)
WW = Week Code (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	60	V	
Gate-Source Voltage		V _{GSS}	±20	V
	T _A = +25°C		17.8	А
Continuous Drain Current (Note 5) V _{GS} = 10V	T _A = +100°C	ID	12.6	
	T _C = +25°C		100.0	А
Continuous Drain Current (Note 6) V _{GS} = 10V	T _C = +100°C	ID	75.9	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	400	А	
Maximum Continuous Body Diode Forward Current (Note 6)	IS	100	А	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	I _{SM}	400	А	
Avalanche Current, L = 0.3mH	I _{AS}	24.2	А	
Avalanche Energy, L = 0.3mH		E _{AS}	87.9	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.94	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{0JA}	51	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	107	W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	1.4	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

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	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			1	1		-	
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	—	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	—	_	±100	nA	$V_{GS} = 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	4.8	6.2	mΩ	V _{GS} = 10V, I _D = 10.5A	
Diode Forward Voltage	V _{SD}		0.8	1.2	V	$V_{GS} = 0V, I_{S} = 21A$	
DYNAMIC CHARACTERISTICS (Note 8)			•			÷	
Input Capacitance	Ciss	_	1721	_			
Output Capacitance	C _{oss}	_	740		pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	49	_			
Gate Resistance	Rq		0.6		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qq	_	27.9	_			
Gate-Source Charge	Qgs		7.4		nC	$V_{DS} = 30V, I_D = 21A, V_{GS} = 10V$	
Gate-Drain Charge	Q _{ad}		7.3				
Turn-On Delay Time	t _{D(ON)}		7.5				
Turn-On Rise Time	t _R		8.2			$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 10.5A, R_q = 4.7\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	_	16.5	—	ns		
Turn-Off Fall Time	tF	_	9.8	_	1	-	
Reverse Recovery Time	t _{RR}	_	37.0	—	ns		
Reverse Recovery Charge	Q _{RR}	_	42.9	—	nC	I _F = 21A, di/dt = 300A/µs	

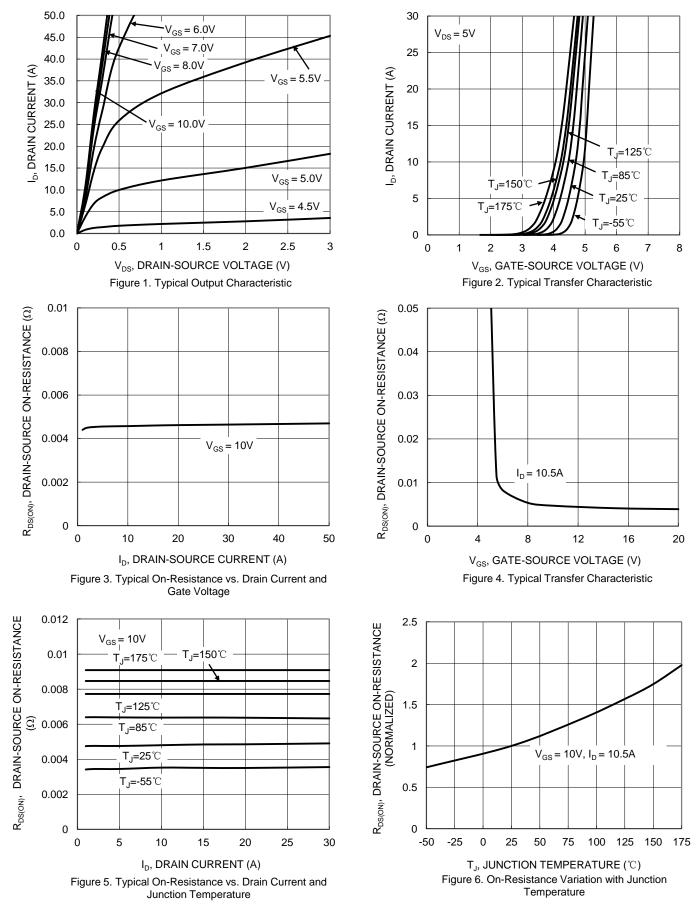
5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



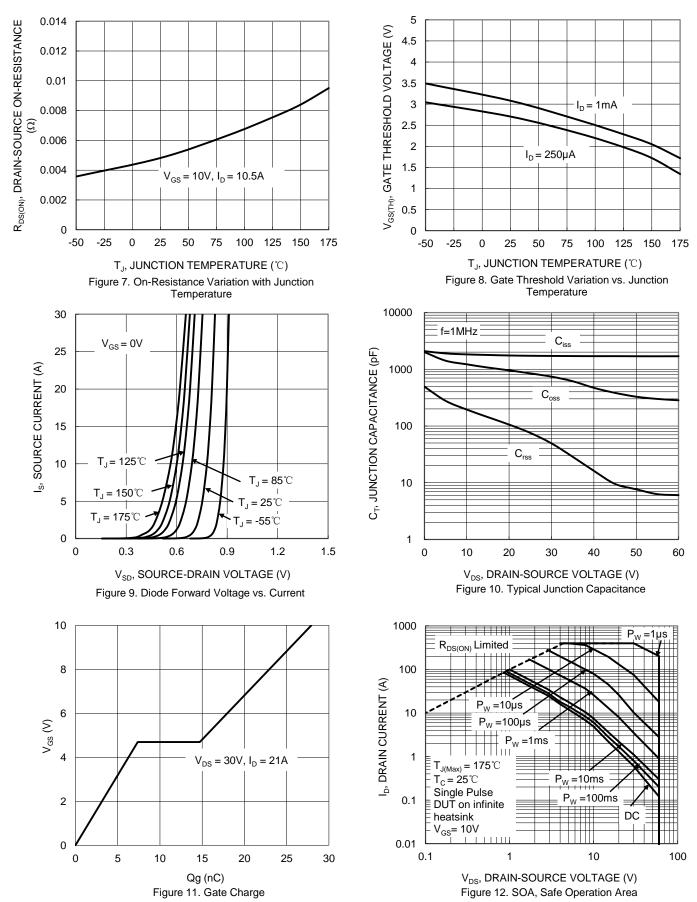
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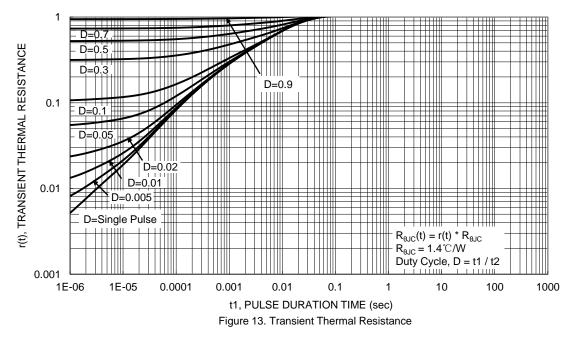
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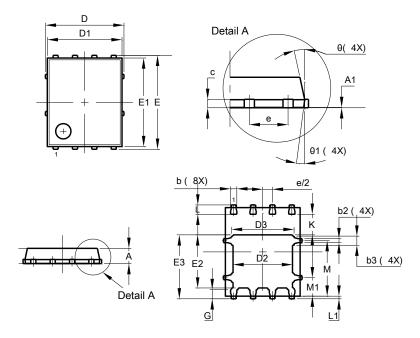




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

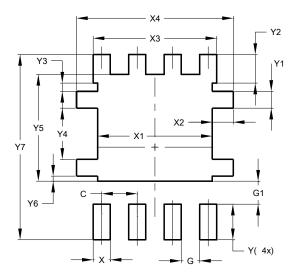


PowerDI5060-8					
			Тур		
A	0.90	1.10	1.00		
A1	0.00 0.05 –				
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	ļ	5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99				
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
X3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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